















MAX3221

SLLS348O -JUNE 1999-REVISED JUNE 2015

MAX3221 3-V to 5.5-V RS-232 Line Driver and Receiver With ±15-kV ESD Protection

Features

- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU V.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates up to 250 kbps
- One Driver and One Receiver
- Low Standby Current: 1 µA Typical
- External Capacitors: 4 x 0.1 µF
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbps)
 - SNx5C3221
- Automatic Power-Down Feature Automatically Disables Drivers for Power Savings

2 Applications

- Battery-Powered, Hand-Held, and Portable Equipment
- Notebooks, Subnotebooks, and Laptops
- **Digital Cameras**
- Mobile Phones and Wireless Devices

3 Description

The MAX3221 device consists of one line driver, one line receiver with dedicated enable pin, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. These devices operate at data signaling rates up to 250 kbps and a maximum of 30-V/µs driver output slew rate.

Flexible control options for power management are available when the serial port is inactive. The automatic power-down feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a

RS-232 signal on the receiver input, the driver output is disabled and the supply current is reduced to 1 µA. The INVALID output notifies the user if an RS-232 signal is present at the receiver input.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
MAX3221xDB	SSOP (32)	6.20 mm × 5.30 mm
MAX3221xPW	TSSOP (32)	5.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Diagram

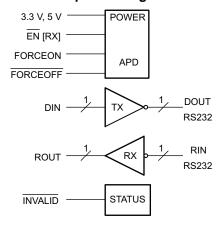




Table of Contents

1	Features 1	8	Detailed Description	11
2	Applications 1		8.1 Overview	
3	Description 1		8.2 Functional Block Diagram	11
4	Revision History2		8.3 Feature Description	11
5	Pin Configuration and Functions		8.4 Device Functional Modes	12
6	Specifications4	9	Application and Implementation	13
•	6.1 Absolute Maximum Ratings 4		9.1 Application Information	13
	6.2 ESD Ratings		9.2 Typical Application	13
	6.3 Recommended Operating Conditions	10	Power Supply Recommendations	14
	6.4 Thermal Information	11	Layout	15
	6.5 Electrical Characteristics – Power		11.1 Layout Guidelines	15
	6.6 Electrical Characteristics – Driver		11.2 Layout Example	15
	6.7 Electrical Characteristics – Receiver	12	Device and Documentation Support	16
	6.8 Electrical Characteristics – Status 6		12.1 Community Resources	16
	6.9 Switching Characteristics – Driver 6		12.2 Trademarks	16
	6.10 Switching Characteristics – Receiver		12.3 Electrostatic Discharge Caution	16
	6.11 Switching Characteristics – Status		12.4 Glossary	16
	6.12 Typical Characteristics 7	13	Mechanical, Packaging, and Orderable	
7	Parameter Measurement Information 8		Information	16

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision N (January 2014) to Revision O

Page

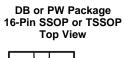
Changes from Revision M (March 2004) to Revision N

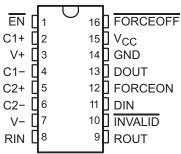
Page

Updated document to new TI data sheet format - no specification changes.
 Deleted Ordering Information table.



5 Pin Configuration and Functions





Pin Functions

P	IN	1/0	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
C1+	2		Desitive terminals of the voltage doubler shares number conseiters
C2+	5	_	Positive terminals of the voltage-doubler charge-pump capacitors
C1-	4		Negative terminals of the voltage devibler shares number conscitors
C2-	6	_	Negative terminals of the voltage-doubler charge-pump capacitors
DIN	11	1	Driver input
DOUT	13	0	RS-232 driver output
EN	1	ı	Low input enables receiver ROUT output. High input sets ROUT to high impedance.
FORCEOFF	16	I	Automatic power-down control input
FORCEON	12	1	Automatic power-down control input
GND	14	_	Ground
INVALID	10	0	Invalid output pin. Output low when all RIN inputs are unpowered.
RIN	8	ı	RS-232 receiver input
ROUT	9	0	Receiver output
V _{CC}	15	_	3-V to 5.5-V supply voltage
V+	3	0	5.5-V supply generated by the charge pump
V-	7	0	-5.5-V supply generated by the charge pump



Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
	V _{CC} to GND		-0.3	6	
	V+ to GND		-0.3	7	V
	V- to GND		0.3	-7	V
	V+ + V- ⁽²⁾			13	
\/	Lawret coellings	DIN, EN, FORCEOFF, and FORCEON to GND	-0.3	6	V
VI	Input voltage	RIN to GND		±25	V
\/	Output valtage	DOUT to GND		±13.2	V
Vo	Output voltage	ROUT to GND	-0.3	$V_{CC} + 0.3$	V
T_{J}	Junction temperature (3)			150	°C
T _{stg}	Storage temperature range		-65	150	

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

				VALUE	UNIT
	Human body model (HBM), per	All pins except 8, 13	±3000		
V _(ESD)	Electrostatic discharge	ANSI/ESDA/JEDEC JS-001 (1)	Pins 8, 13	±15,000	V
* (ESD)	Lissinssians districting	Charged-device model (CDM), per JED C101 ⁽²⁾	PEC specification JESD22-	±1500	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

(see Figure 8)(1)

				MIN	NOM	MAX	UNIT
	Cupply voltage		$V_{CC} = 3.3 \text{ V}$	3	3.3	3.6	V
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	v
V	DIN, FORCEOFF,	$V_{CC} = 3.3 \text{ V}$	2			V	
V _{IH}	Driver flight-level input voltage	FORCEON, EN	$V_{CC} = 5 V$	2.4			v
V _{IL}	Driver low-level input voltage	DIN, FORCEOFF, FORCEON, EN				0.8	V
VI	Driver input voltage	DIN, FORCEOFF, FORCEON, EN		0		5.5	V
	Receiver input voltage			-25		25	
т	T Operating free air temperature		MAX3221C	0		70	°C
T _A	Operating free-air temperature		MAX3221I	-40		85	

(1) Test conditions are C1-C4 = 0.1 μ F at V_{CC} = 3.3 $V \pm 0.3$ V; C1 = 0.047 μ F, C2-C4 = 0.33 μ F at V_{CC} = 5 $V \pm 0.5$ V.

V+ and V− can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V. Maximum power dissipation is a function of $T_J(max)$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A) / R_{\theta JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

		MAX	MAX3221		
	THERMAL METRIC ⁽¹⁾	DB (SSOP)	PW (TSSOP)	UNIT	
		16 PINS	16 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	98.0	106.4	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	48.3	41.1	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	48.7	51.4	°C/W	
ΨЈТ	Junction-to-top characterization parameter	10.1	3.9	°C/W	
ΨЈВ	Junction-to-board characterization parameter	48.1	50.9	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics - Power

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER		TEST	CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I	Input leakage current	FORCEOFF, FORCEON, EN				±0.01	±1	μΑ
		Automatic power-down disabled		No load, FORCEOFF and FORCEON at V _{CC}		0.3	1	mA
lcc	Supply current	Powered off	No load,	No load, FORCEOFF at GND		1	10	
I _{CC}		Automatic power-down enabled	V _{CC} = 3.3 V to 5 V	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

6.6 Electrical Characteristics – Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V _{OH}	High-level output voltage	D_{OUT} at $R_L = 3 \text{ k}\Omega$ to GND,	$D_{IN} = GND$	5	5.4		V
V _{OL}	Low-level output voltage	D_{OUT} at $R_L = 3 \text{ k}\Omega$ to GND,	$D_{IN} = V_{CC}$	- 5	-5.4		V
I _{IH}	High-level input current	$V_I = V_{CC}$			±0.01	±1	μA
I _{IL}	Low-level input current	V _I at GND			±0.01	±1	μΑ
		V _{CC} = 3.6 V	$V_O = 0 V$		±35	±60	A
Ios	Short-circuit output current ⁽³⁾	V _{CC} = 5.5 V	$V_O = 0 V$		±35	±60	mA
r _O	Output resistance	V _{CC} , V+, and V- = 0 V	V _O = ±2 V	300	10M		Ω
	Output lealings aurent	FORCEOUT CND	$V_O = \pm 12 \text{ V},$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$			±25	^
loff	Output leakage current	FORCEOFF = GND	V _O = ±12 V, V _{CC} = 4.5 V to 5.5 V			±25	μA

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.



6.7 Electrical Characteristics – Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.6	$V_{\rm CC}-0.1$		V
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
\/	Docitive going input threshold voltage	V _{CC} = 3.3 V		1.5	2.4	V
V_{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		1.8	2.4	V
\/	Negative going input threehold voltage	V _{CC} = 3.3 V	0.6	1.1		V
V_{IT-}	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.4		V
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.5		V
I _{off}	Output leakage current	FORCEOFF = 0 V		±0.05	±10	μΑ
r _i	Input resistance	$V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

6.8 Electrical Characteristics – Status

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)⁽¹⁾

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}			2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-2.7			٧
V _{T(invalid)}	Receiver input threshold for $\overline{\text{INVALID}}$ low-level output voltage	FORCEON = GND, FORCEOFF = V _{CC}	-0.3		0.3	٧
V _{OH}	INVALID high-level output voltage	$I_{OH} = -1 \text{ mA},$ FORCEON = GND, $FORCEOFF = V_{CC}$	V _{CC} – 0.6			V
V _{OL}	INVALID low-level output voltage	$I_{OH} = -1 \text{ mA},$ FORCEON = GND, $FORCEOFF = V_{CC}$			0.4	V

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

6.9 Switching Characteristics – Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

	9 11 7	0 1	1 \		,		
	PARAMETER	TEST (CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
Maximum data rate		kΩ,	150	250		kbps	
t _{sk(p)}	Pulse skew ⁽³⁾	C_L = 150 to 2500 pF, see Figure 4	C_L = 150 to 2500 pF, R_L = 3 k Ω to 7 k Ω , see Figure 4		100		ns
SR(tr)	Slew rate, transition region	$V_{CC} = 3.3 \text{ V},$	$C_L = 150 \text{ to } 1000 \text{ pF}$	6		30	\//uo
SK(II)	(see Figure 3)	$R_L = 3 k\Omega$ to $7 k\Omega$	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega$ $C_L = 150 \text{ to } 2500 \text{ pF}$			30	V/µs

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.



6.10 Switching Characteristics – Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
t _{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, see Figure 5		150		ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, see Figure 5		150		ns
t _{en}	Output enable time	C_L = 150 pF, R_L = 3 k Ω , see Figure 6		200		ns
t _{dis}	Output disable time	C_L = 150 pF, R_L = 3 k Ω , see Figure 6		200		ns
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 5		50		ns

- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH} t_{PHL}|$ of each channel of the same device.

Switching Characteristics – Status

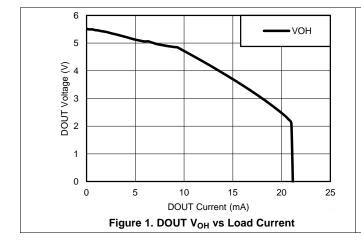
over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)(1)

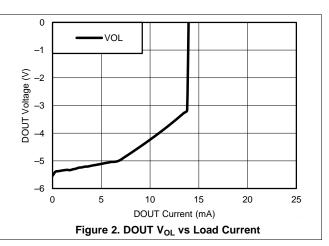
	PARAMETER	MIN	TYP ⁽²⁾	MAX	UNIT
t _{valid}	Propagation delay time, low- to high-level output		1		μs
t _{invalid}	Propagation delay time, high- to low-level output		30		μs
t _{en}	Supply enable time		100		μs

- Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.
- All typical values are at $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$, and $T_A = 25 ^{\circ}\text{C}$.

6.12 Typical Characteristics

 $V_{CC} = 3.3 \text{ V}$

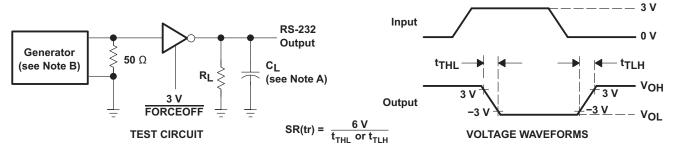




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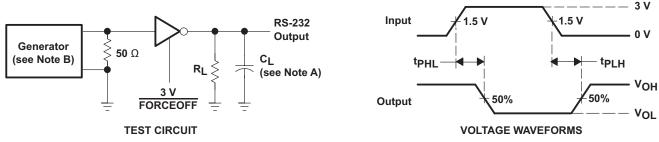


7 Parameter Measurement Information



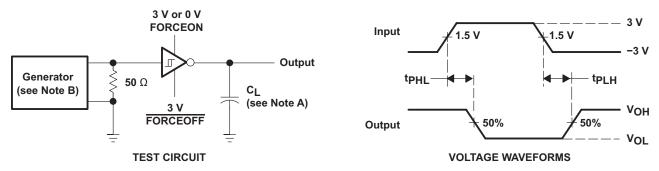
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbps, Z_O = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Driver Slew Rate



- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbps, Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 4. Driver Pulse Skew

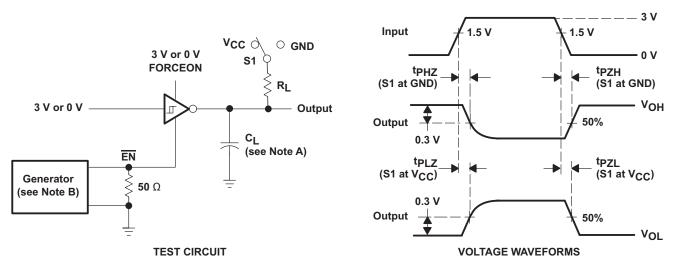


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 5. Receiver Propagation Delay Times



Parameter Measurement Information (continued)

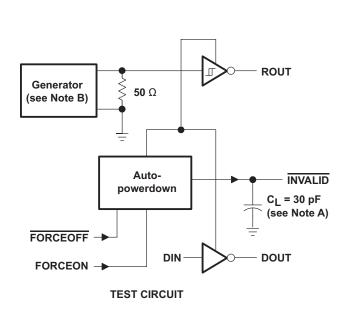


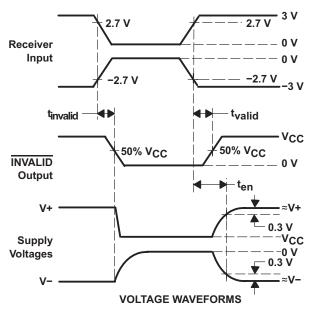
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- D. t_{PZL} and t_{PZH} are the same as t_{en} .

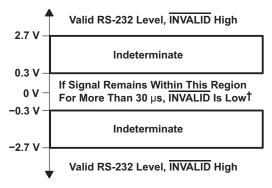
Figure 6. Receiver Enable and Disable Times



Parameter Measurement Information (continued)







 $\ensuremath{^{\dagger}}$ Auto-powerdown disables drivers and reduces supply current to 1 $\mu A.$

Figure 7. INVALID Propagation Delay Times and Driver Enabling Time



8 Detailed Description

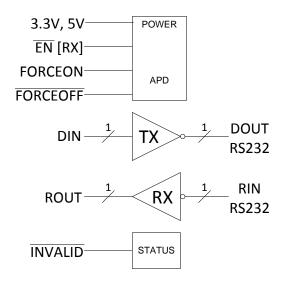
8.1 Overview

The MAX3221 device is a one-driver and one-receiver RS-232 interface device. All RS-232 inputs and outputs are protected to ±15 kV using the Human Body Model. The charge pump requires only four small 0.1-µF capacitors for operation from a 3.3-V supply. The MAX3221 is capable of running at data rates up to 250 kbps, while maintaining RS-232-compliant output levels.

Automatic power-down can be disabled when FORCEON and FORCEOFF are high. With automatic power-down plus enabled, the device activates automatically when a valid signal is applied to any receiver input. The device can automatically power down the driver to save power when the RIN input is unpowered.

INVALID is high (valid data) if receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μs. INVALID is low (invalid data) if receiver input voltages are between -0.3 V and 0.3 V for more than 30 μs. Refer to Figure 7 for receiver input levels.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Power

The power block increases, inverts, and regulates voltage at V+ and V- pins using a charge <u>pump that requires</u> four external capacitors. <u>Aut</u>o-power-down feature for driver is controlled by FORCEON and FORCEOFF inputs. Receiver is controlled by <u>EN</u> input. See <u>Table 1</u> and <u>Table 2</u>

When MAX3221 is unpowered, it can be safely connected to an active remote RS232 device.

8.3.2 RS232 Driver

One driver interfaces standard logic level to RS232 levels. DIN input must be valid high or low.

8.3.3 RS232 Receiver

One receiver interfaces RS232 levels to standard logic levels. An open input will result in a high output on ROUT. RIN input includes an internal standard RS232 load. A logic high input on the $\overline{\text{EN}}$ pin will shutdown the receiver output.

8.3.4 RS232 Status

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The $\overline{\text{INVALID}}$ output goes low when RIN input is unpowered for more than 30 μ s. The $\overline{\text{INVALID}}$ output goes high when receiver has a valid input. The $\overline{\text{INVALID}}$ output is active when V_{cc} is powered irregardless of FORCEON and $\overline{\text{FORCEOFF}}$ inputs (see Table 3).

Draduat Folder Links, M



8.4 Device Functional Modes

Table 1, Table 2, and Table 3 show the behavior of the driver, receiver, and INVALID(activelow) features under all possible relevant combinations of inputs.

Table 1. Driver⁽¹⁾

		INPUTS		OUTPUT			
DIN	FORCEON	FORCEOFF	FORCEOFF VALID RIN RS-232 LEVEL		DRIVER STATUS		
Х	X	L	X	Z	Powered off		
L	Н	Н	X	Н	Normal operation with		
Н	Н	Н	X	L	automatic power down disabled		
L	L	Н	Yes	Н	Normal operation with		
Н	L	Н	Yes	L	automatic power down enabled		
L	L	Н	No	Z	Powered off by		
Н	L	Н	No	Z	automatic power down feature		

(1) H = high level, L = low level, X = irrelevant, Z = high impedance, Yes = |RIN| > 2.7 V, No = |RIN| < 0.3 V

Table 2. Receiver⁽¹⁾

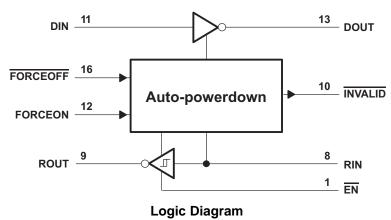
	INPUTS	3	OUTPUT	
RIN	EN	VALID RIN RS-232 LEVEL	ROUT	RECEIVER STATUS
Х	Н	X	Z	Output off
L	L	X	Н	
Н	L	X	L	Normal operation
Open	L	No	Н	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

Table 3. INVALID (1)

	INPUTS									
RIN	FORCEON	EN	INVALID							
L	X	X	X	Н						
Н	X	X	X	Н						
Open	X	X	X	L						

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off



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9 Application and Implementation

NOTE

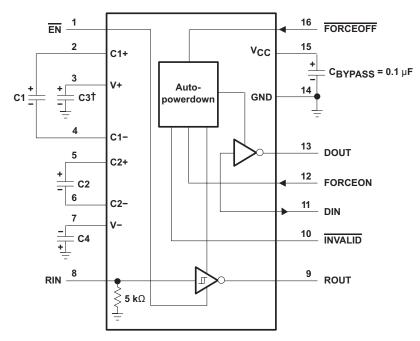
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The MAX3221 line driver and receiver is a specialized device for 3-V to 5.5-V RS-232 communication applications. This application is a generic implementation of this device with all required external components. For proper operation, add capacitors as shown in Figure 8.

9.2 Typical Application

ROUT and DIN connect to UART or general purpose <u>logic lines</u>. FORCEON and $\overline{\text{FORCEOFF}}$ may be connected general purpose logic lines or tied to ground or V_{CC} . INVALID may be connected to a general purpose logic line or <u>left unconnected</u>. RIN and DOUT lines connect to a RS232 connector or cable. DIN, FORCEON, and FORCEOFF inputs must not be left unconnected.



[†]C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

VCC vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
3.3 V ± 0.3 V 5 V ± 0.5 V	0.1 μF 0.047 μF	0.1 μF 0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μF

Figure 8. Typical Operating Circuit and Capacitor Values



Typical Application (continued)

9.2.1 Design Requirements

- Recommended V_{CC} is 3.3 V or 5 V.
 - 3 V to 5.5 V is also possible
- · Maximum recommended bit rate is 250 kbps.
- Use capacitors as shown in Figure 8.

9.2.2 Detailed Design Procedure

- DIN, FORCEOFF and FORCEON inputs must be connected to valid low or high logic levels.
- Select capacitor values based on VCC level for best performance.

9.2.3 Application Curve

Curves for V_{CC} of 3.3 V and 250 kbps alternative bit data stream.

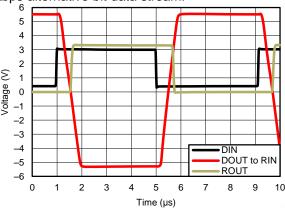


Figure 9. 250-kbps Driver to Receiver Loopback Timing Waveform, V_{CC} = 3.3 V

10 Power Supply Recommendations

TI recommends a 0.1-µF capacitor to filter noise on the power supply pin. For additional filter capability, a 0.01-µF capacitor may be added in parallel as well. Power supply input voltage is recommended to be any valid level in *Recommended Operating Conditions*.



11 Layout

11.1 Layout Guidelines

Keep the external capacitor traces short. This is more important on C1 and C2 nodes that have the fastest rise and fall times.

11.2 Layout Example

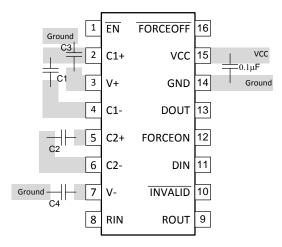


Figure 10. Layout Diagram



12 Device and Documentation Support

12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Lise

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.2 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.





24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3221CDB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CDBE4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221CPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MA3221C	Sample
MAX3221IDB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IDBE4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IDBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IDBRE4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample
MAX3221IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Sample



PACKAGE OPTION ADDENDUM

24-Aug-2018

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3221IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	MB3221I	Samples
MAX3221IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB3221I	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF MAX3221:



PACKAGE OPTION ADDENDUM

24-Aug-2018

● Enhanced Product: MAX3221-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 20-Dec-2018

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All ulmensions are nominal	All differsions are nominal											
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3221CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MAX3221IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MAX3221IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
MAX3221IPWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 20-Dec-2018



*All dimensions are nominal

7 til dilliciololio are nominal							
Device	Device Package Type		g Pins SPQ		Length (mm)	Width (mm)	Height (mm)
MAX3221CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
MAX3221IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
MAX3221IPWR	TSSOP	PW	16	2000	364.0	364.0	27.0
MAX3221IPWRG4	TSSOP	PW	16	2000	367.0	367.0	35.0

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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